

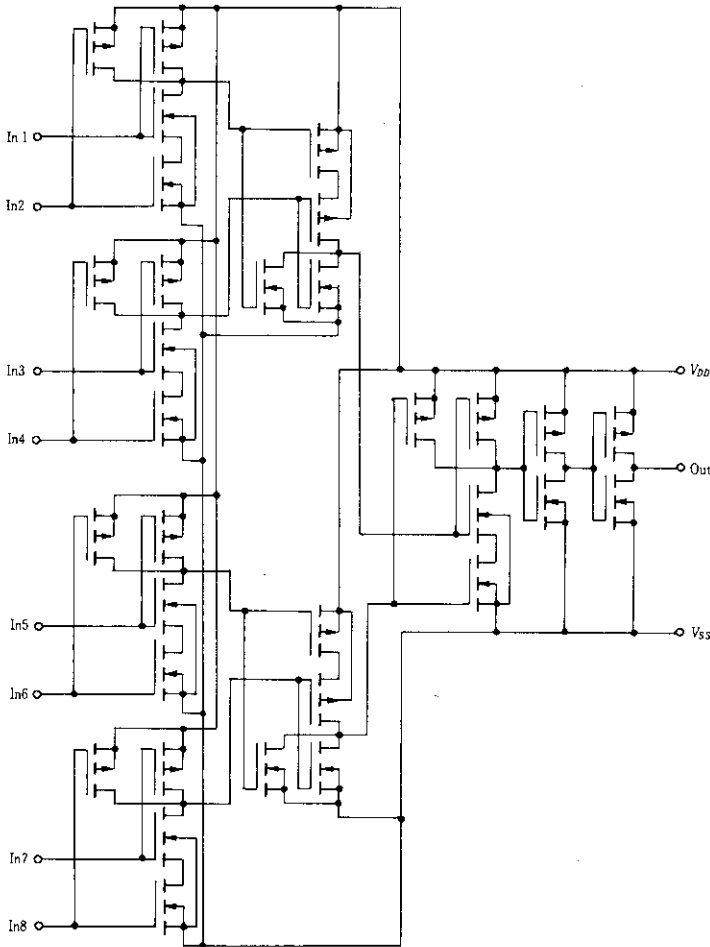
# HD14068B

## 8-input NAND Gate

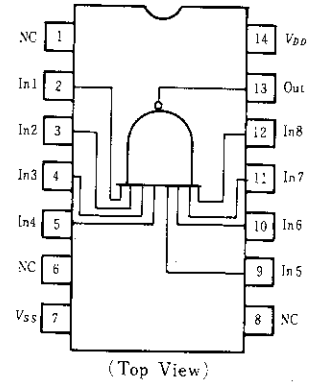
### FEATURES

- Quiescent Current = 0.5nA typ/pkg @5V
- Noise Immunity = 45% of  $V_{DD}$  typ
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for Pin Replacements for CD4068B and MC14068B Series

### CIRCUIT SCHEMATIC



### PIN ARRANGEMENT



**ELECTRICAL CHARACTERISTICS**

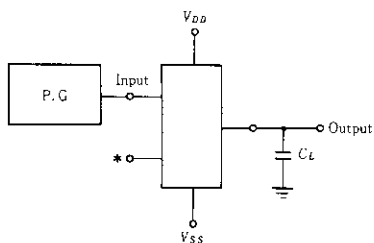
Characteristic	Symbol	Test Conditions	-40°C		25°C			85°C		Unit	
			min	max	min	typ	max	min	max		
Output Voltage	V <sub>OL</sub>	V <sub>DD</sub> (V)								V	
		5.0		0.05	—	0	0.05	—	0.05		
		10	V <sub>in</sub> = V <sub>DD</sub>	—	0.05	—	0	0.05	—		0.05
	V <sub>OH</sub>	5.0	V <sub>in</sub> = 0	4.95	—	4.95	5.0	—	4.95	—	V
		10		9.95	—	9.95	10	—	9.95	—	
		15		14.95	—	14.95	15	—	14.95	—	
Input Voltage	V <sub>IL</sub>	V <sub>DD</sub> (V)								V	
		5.0	V <sub>out</sub> = 4.5V	—	1.5	—	2.25	1.5	—		1.5
		10	V <sub>out</sub> = 9.0V	—	3.0	—	4.50	3.0	—		3.0
	V <sub>IH</sub>	5.0	V <sub>out</sub> = 0.5V	3.5	—	3.5	2.75	—	3.5	—	V
		10	V <sub>out</sub> = 1.0V	7.0	—	7.0	5.50	—	7.0	—	
		15	V <sub>out</sub> = 1.5V	11.0	—	11.0	8.25	—	11.0	—	
Output Drive Current	I <sub>OH</sub>	V <sub>DD</sub> (V)								mA	
		5.0	V <sub>OH</sub> = 2.5V	-2.5	—	-2.1	-4.2	—	-1.7		—
		5.0	V <sub>OH</sub> = 4.6V	-0.52	—	-0.44	-0.88	—	-0.36		—
	I <sub>OL</sub>	5.0	V <sub>OL</sub> = 0.4V	0.52	—	0.44	0.88	—	0.36	—	mA
		10	V <sub>OL</sub> = 0.5V	1.3	—	1.1	2.25	—	0.9	—	
		15	V <sub>OL</sub> = 1.5V	3.6	—	3.0	8.8	—	2.4	—	
Input Current	I <sub>in</sub>	15		±0.3	—	±0.00001	±0.3	—	±1.0	μA	
Input Capacitance	C <sub>in</sub>	—	V <sub>in</sub> = 0	—	—	5.0	7.5	—	—	pF	
Quiescent Current	I <sub>DD</sub>	5.0	Zero Signal, per Package	—	1.0	0.0005	1.0	—	7.5	—	μA
		10		—	2.0	0.0010	2.0	—	15.0		
		15		—	4.0	0.0015	4.0	—	30.0		
Total Supply Current*	I <sub>T</sub>	5.0	Dynamic + I <sub>DD</sub>	—	—	0.3	—	—	—	μA	
		10	C <sub>L</sub> = 50pF, f = 1 kHz	—	—	0.6	—	—	—		
		15		—	—	0.9	—	—	—		

\* To calculate total supply current at frequency other than 1kHz.  
 @ V<sub>DD</sub> = 5.0V I<sub>T</sub> = (0.3 μA/kHz) f + I<sub>DD</sub> @ V<sub>DD</sub> = 10V I<sub>T</sub> = (0.6 μA/kHz) f + I<sub>DD</sub> @ V<sub>DD</sub> = 15V I<sub>T</sub> = (0.9 μA/kHz) f + I<sub>DD</sub>

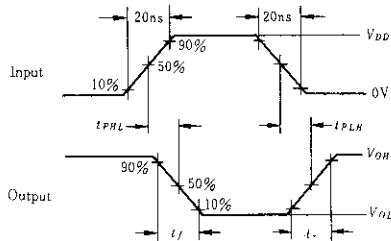
**SWITCHING CHARACTERISTICS (C<sub>L</sub> = 50pF, T<sub>a</sub> = 25°C)**

Characteristic	Symbol	V <sub>DD</sub> (V)	min	typ	max	Unit
Output Rise Time	t <sub>r</sub>	5.0	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Output Fall Time	t <sub>f</sub>	5.0	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Propagation Delay Time	t <sub>PLH</sub>	5.0	—	200	400	ns
		10	—	80	160	
		15	—	60	120	
	t <sub>PHL</sub>	5.0	—	200	400	ns
		10	—	80	160	
		15	—	60	120	

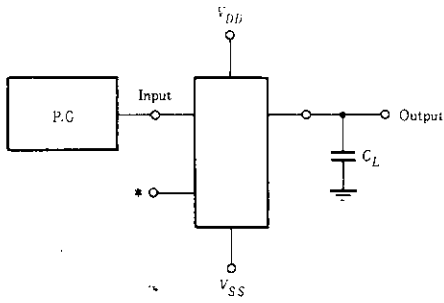
**SWITCHING TIME TEST CIRCUIT**



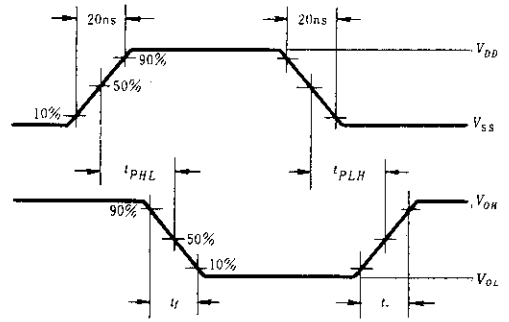
\*: All unused inputs of AND, NAND gates must be connected to V<sub>DD</sub>.



■ SWITCHING TIME TEST CIRCUIT

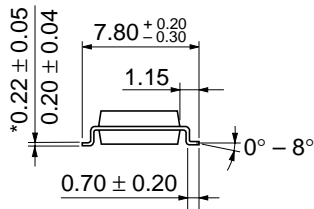


\* All unused inputs of AND, NAND gates must be connected to  $V_{DD}$ .



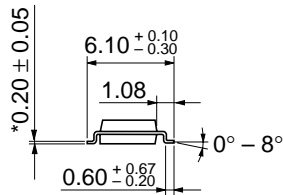
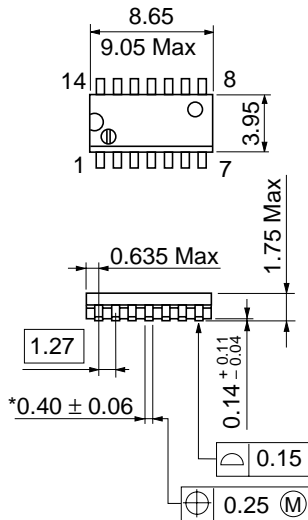


Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g



Hitachi Code	FP-14DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.23 g

\*Dimension including the plating thickness  
Base material dimension



Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.13 g

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